

ISOLATED DIODE ARRAY

Qualified per MIL-PRF-19500/474

DEVICES

1N5768

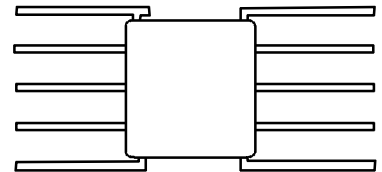
LEVELS

**JAN
 JANTX
 JANTXV**

DESCRIPTION

These low capacitance diode arrays with common cathode are multiple, discrete, isolated junctions fabricated by a planar process and mounted in a 10-PIN package for use as steering diodes protecting up to eight I/O ports from ESD, EFT, or surge by directing them to the positive side of the power supply line (see figure 1). This circuit application is further complimented by the 1N5770 (separate data sheet) that has a common anode. An external TVS diode may be added between the positive supply line and ground to prevent overvoltage on the supply rail. They may also be used in fast switching core-driver applications. This includes computers and peripheral equipment such as magnetic cores, thin-film memories, plated-wire memories, etc., as well as decoding or encoding applications. These arrays offer many advantages of integrated circuits such as high-density packaging and improved reliability. This is a result of fewer pick and place operations, smaller footprint, smaller weight, and elimination of various discrete packages that may not be as user friendly in PC board mounting.

IMPORTANT: For the most current data, consult *MICROSEMI's* website: <http://www.microsemi.com>



**10-PIN Ceramic
 Flat Pack**

FEATURES

- Hermetic Ceramic Package
- Isolated Diodes to Eliminate Cross-Talk Voltages
- High Breakdown Voltage $V_{BR} > 60 \text{ V}$ at $10 \mu\text{A}$
- Low Leakage $I_R < 100\text{nA}$ at 40 V
- Low Capacitance $C < 4.0 \text{ pF}$
- Options for screening in accordance with MIL-PRF-19500/474 for JAN, JANTX, JANTXV, the prefixes respectively to part numbers.

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APPLICATIONS / BENEFITS

- High Frequency Data Lines
- RS-232 & RS-422 Interface Networks
- Ethernet: 10 Base T
- Computer I/O Ports
- LAN
- Switching Core Drivers
- IEC 61000-4 Compatible (see circuit in figure 1)

61000-4-2 ESD : Air 15kV, contact 8kW

61000-4-4 (EFT) : 40A – 5/50 ns

61000-4-5 (surge): 12A 8/20 μ s

MAXIMUM RATINGS

- V_{BR} Reverse Breakdown Voltage 60 V min (Notes 1 & 2)
- I_O Continuous Forward Current 300 mA (Notes 1 & 3)
- I_{FSM} Forward Surge Current ($t_p=1/120$ s) 500 mA (Note 1)
- 400 mW Power Dissipation per Junction @ 25°C
- 500 mW Power Dissipation per Package @ 25°C (Note 4)
- Operating Junction Temperature range –65 to +150°C
- Storage Temperature range of –65 to +200°C

NOTE 1: Each Diode

NOTE 2: Pulsed: PW = 100 ms max; duty cycle <20%

NOTE 3: Derate at 2.4 mA/°C above +25°C

NOTE 4: Derate at 4.0 mW/°C above +25°C

MECHANICAL AND PACKAGING

- 10-PIN Ceramic Flat Pack
- Weight 0.25 grams (approximate)
- Marking: Logo, part number, date code and dot identifying pin #1
- Carrier Tubes; 19 pcs (standard)

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ELECTRICAL CHARACTERISTICS (Per Diode) @ 25°C unless otherwise specified

PART NUMBER	MAXIMUM FORWARD VOLTAGE V_{F1} $I_F = 100 \text{ mA}$ (Note 1)	MAXIMUM FORWARD VOLTAGE V_{F2} $I_F = 500 \text{ mA}$ (Note 1)	MAXIMUM REVERSE CURRENT I_{R1} $V_R = 40 \text{ V}$	MAXIMUM CAPACITANCE (PIN TO PIN) C_t $V_R = 0 \text{ V}$ $F = 1 \text{ MHz}$	MAXIMUM FORWARD RECOVERY TIME t_{fr} $I_F = 500 \text{ mA}$	MAXIMUM REVERSE RECOVERY TIME t_{rr} $I_F = I_R = 200 \text{ mA}$ $I_{rr} = 20 \text{ mA}$ $R_T = 100 \text{ ohms}$
	Vdc	Vdc	$\mu\text{A dc}$	pF	ns	ns
1N5768	1	1.5	0.1	4.0	40	20

NOTE 1: Pulsed: $P_w = 300 \mu\text{s} \pm 50 \mu\text{s}$, duty cycle $\leq 2\%$, 90 μs after leading edge.

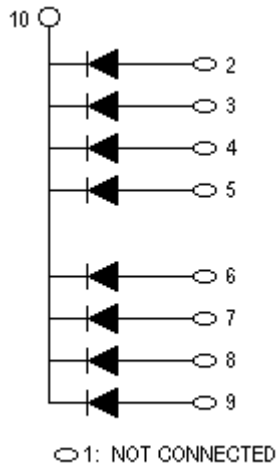
SYMBOLS & DEFINITIONS

Symbol	DEFINITION
V_{BR}	Minimum Breakdown Voltage: The minimum voltage the device will exhibit at a specified current.
V_F	Maximum Forward Voltage: The maximum forward voltage the device will exhibit at a specified current.
I_R	Maximum Reverse Current: The maximum reverse current that will flow at the specified voltage and temperature.
I_{FSM}	Forward Surge Current: The peak forward surge current at a specified pulse width
C_t	Capacitance: The capacitance of the diode as defined @ 0 volts at a frequency of 1 MHz and stated in picofarads.

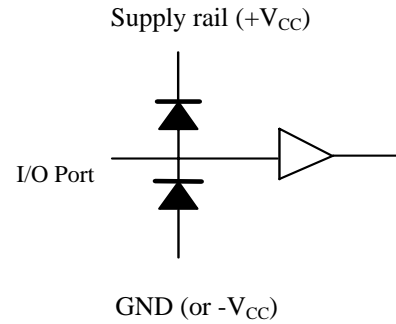
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SCHEMATIC



CIRCUIT



STEERING DIODE APPLICATION

FIGURE 1

PACKAGE DIMENSIONS

